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PLCC TYPE LED LAMPS

LRGB9Q53/R1/TR1-J

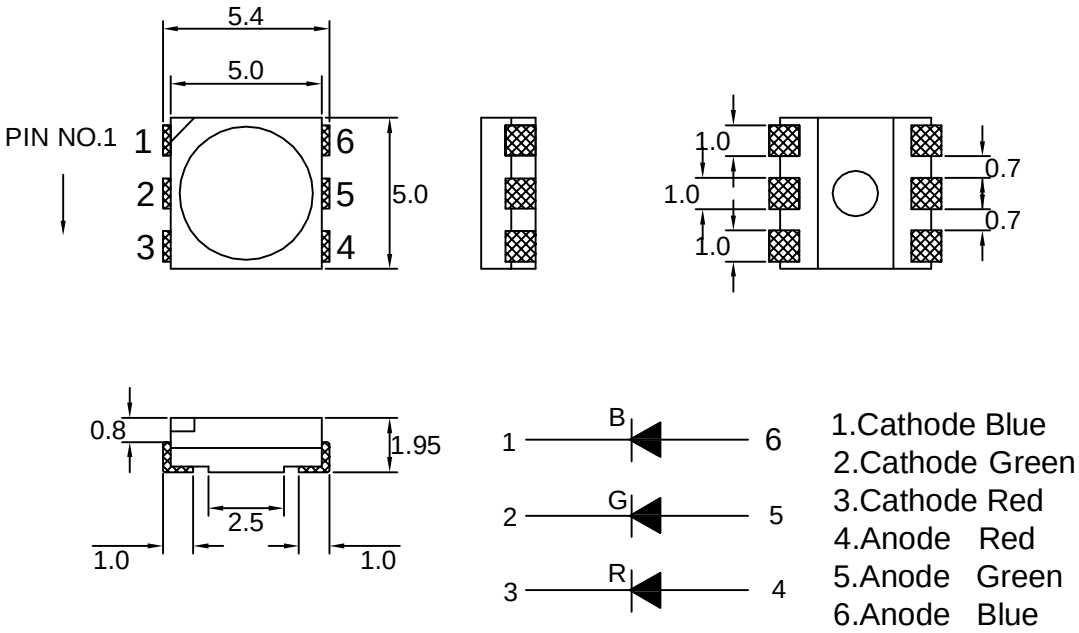
DATA SHEET

DOC. NO : QW0905-LRGB9Q53/R1/TR1-J

REV. : A

DATE : 22 - Oct. - 2005

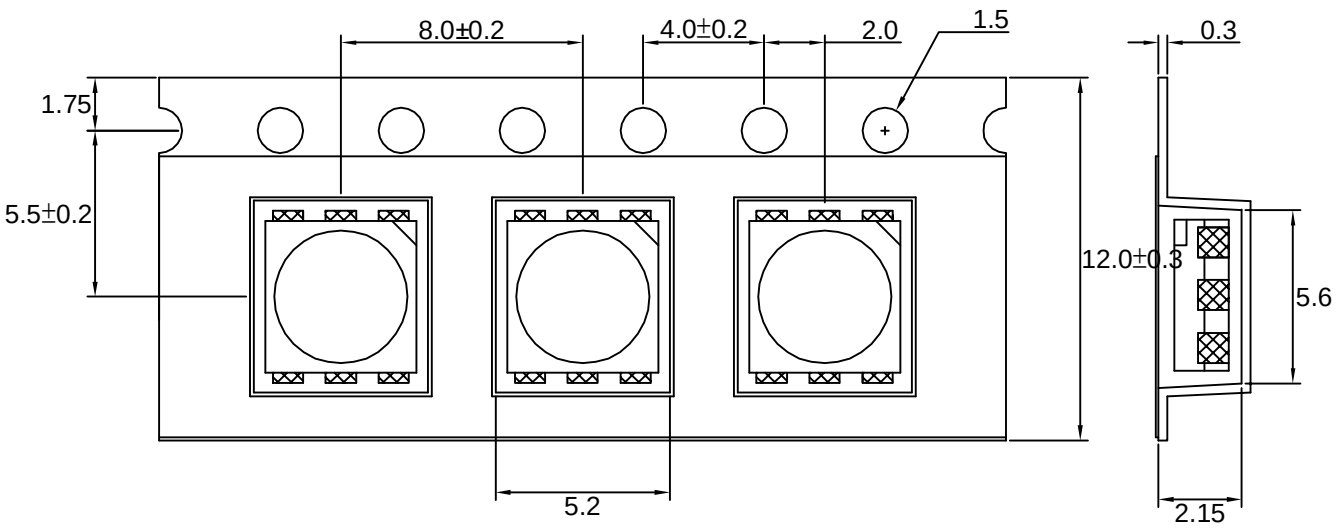
Package Dimensions



1.Cathode Blue
2.Cathode Green
3.Cathode Red
4.Anode Red
5.Anode Green
6.Anode Blue

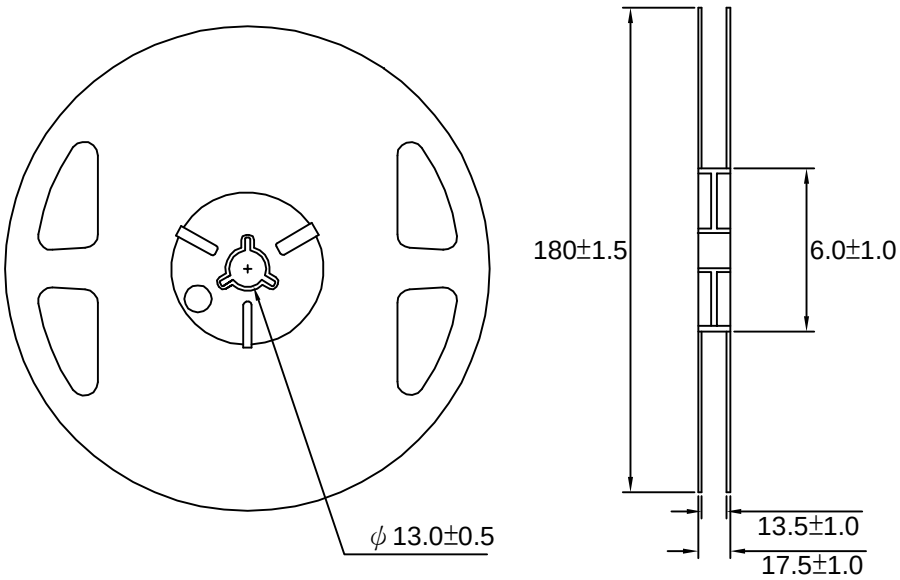
Note : 1.All dimension are in millimeter tolerance is ±0.2mm unless otherwise noted.
2.Specifications are subject to change without notice.

Carrier Type Dimensions



Note : The tolerances unless mentioned is ±0.1mm,Angle ± 0.5. Unit=mm.

Reel Dimensions



Absolute Maximum Ratings at Ta=25 ℃

Parameter	Symbol	Absolute Maximum Ratings			UNIT
		URF	DGM	DBK	
Forward Current	IF	50	30	30	mA
Peak Forward Current Duty 1/10@10KHz	IFP	130	100	100	mA
Power Dissipation	PD	120	120	120	mW
Reverse Current @5V	Ir	10	50	50	μA
Electrostatic Discharge	ESD	2000	1000	1000	V
Operating Temperature	Topr	-20 ~ +80			℃
Storage Temperature	Tstg	-30 ~ +100			℃
Soldering Temperature	Tsol	Max 260℃ for 5 sec Max			

Typical Electrical & Optical Characteristics (Ta=25 ℃)

PART NO	MATERIAL	COLOR		Dominant wave length λ Dnm	Spectral halfwidth △λ nm	Forward voltage @20mA(V)			Luminous intensity @20mA(mcd)		Viewing angle 2θ 1/2 (deg)
		Emitted	Lens			Min.	Typ.	Max.	Min.	Typ.	
LRGB9Q53/R1/TR1-J	AlGaInP	Red	Water Clear	630	20	1.5	----	2.4	80	200	120
	InGaN/GaN	Green		525	36	----	3.5	4.0	125	320	120
	InGaN/GaN	Blue		470	30	----	3.5	4.0	80	200	120

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.
2. The luminous intensity data did not including ±15% testing tolerance.

Typical Electro-Optical Characteristics Curve

URF CHIP

Fig.1 Forward current vs. Forward Voltage

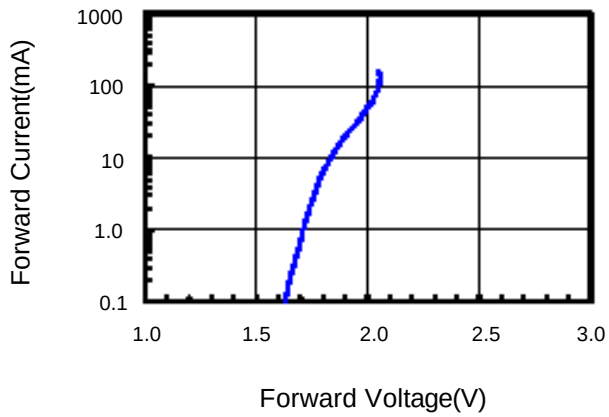


Fig.2 Relative Intensity vs. Forward Current

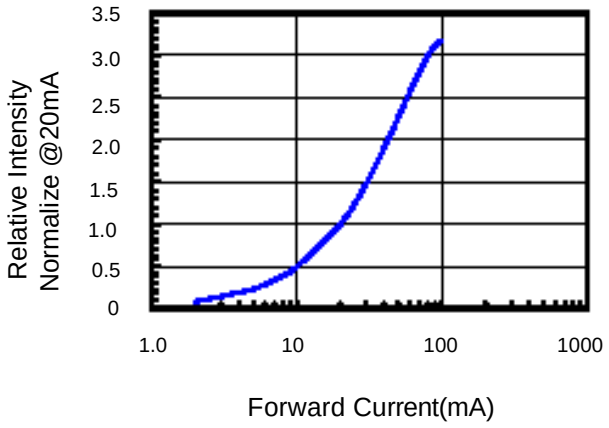


Fig.3 Forward Voltage vs. Temperature

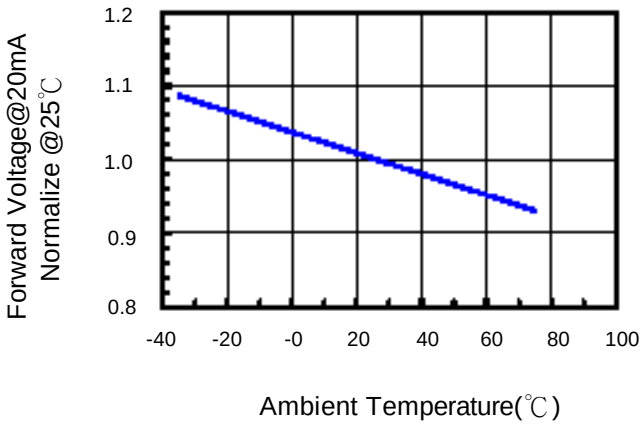


Fig.4 Relative Intensity vs. Temperature

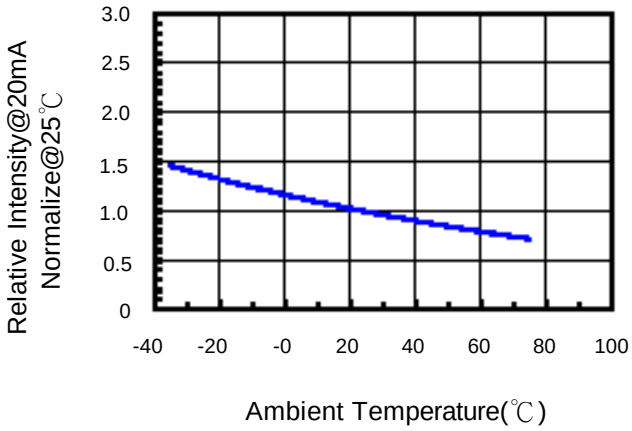


Fig.5 Relative Intensity vs. Wavelength

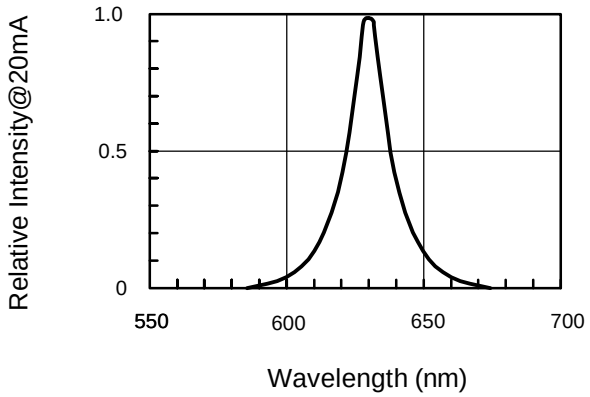
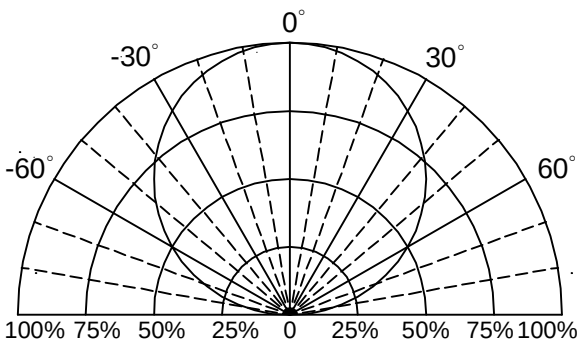


Fig.6 Directive Radiation



Typical Electro-Optical Characteristics Curve

DGM CHIP

Fig.1 Forward current vs. Forward Voltage

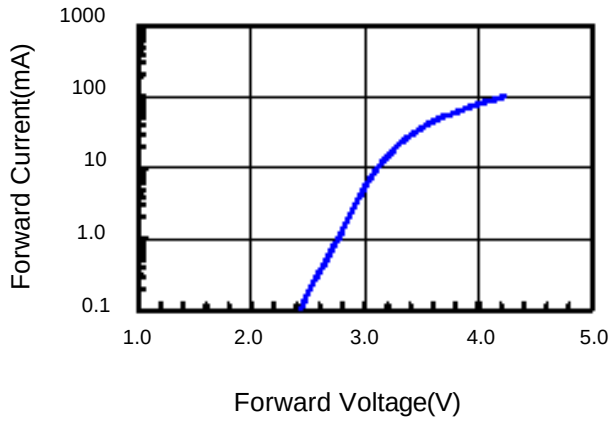


Fig.2 Relative Intensity vs. Forward Current

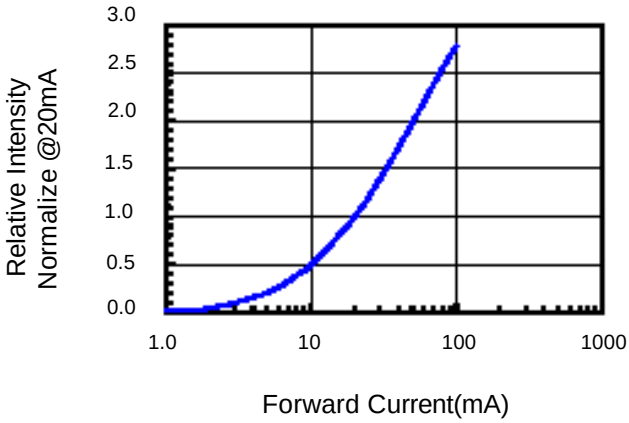


Fig.3 Forward Voltage vs. Temperature

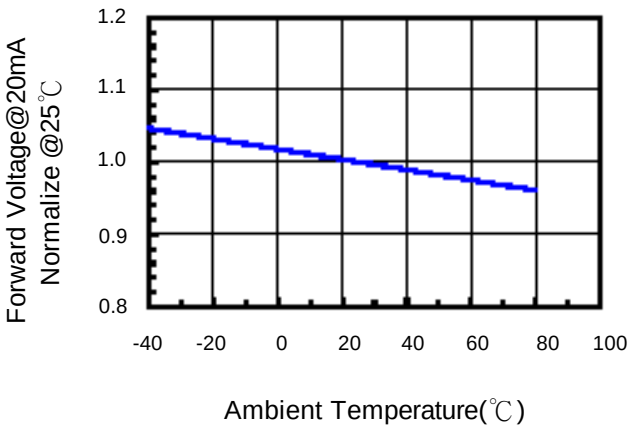


Fig.4 Relative Intensity vs. Temperature

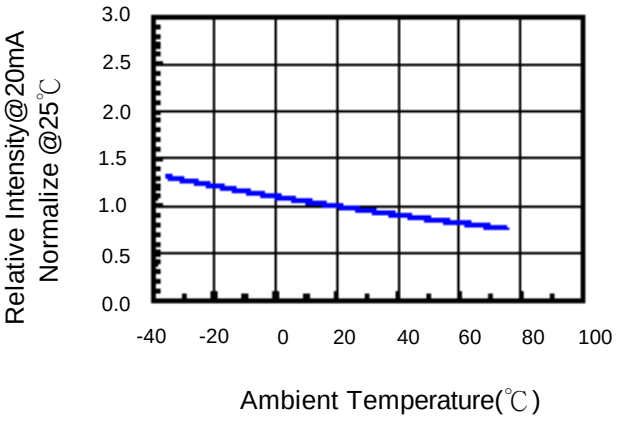


Fig.5 Relative Intensity vs. Wavelength

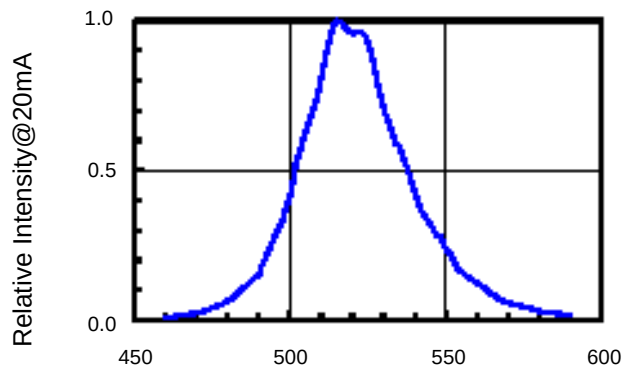
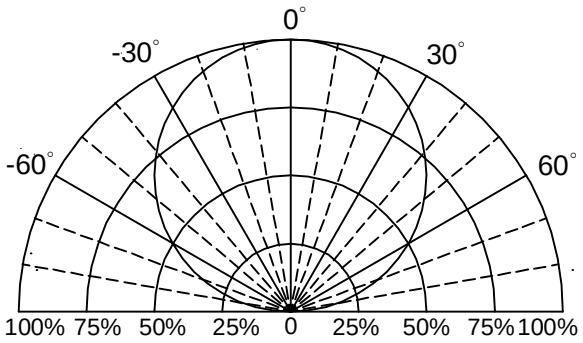


Fig.6 Directive Radiation



Typical Electro-Optical Characteristics Curve

DBK CHIP

Fig.1 Forward current vs. Forward Voltage

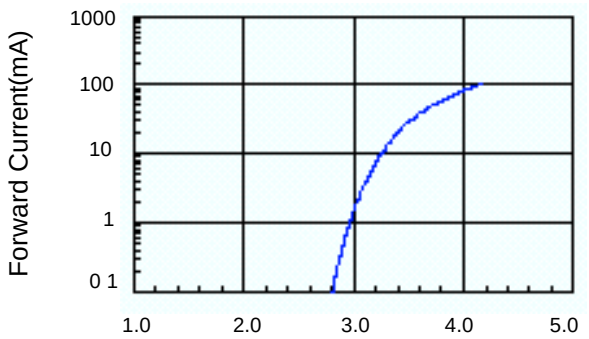


Fig.2 Relative Intensity vs. Forward Current

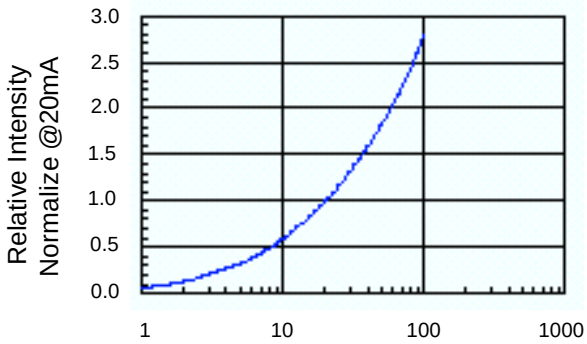


Fig.3 Forward Voltage vs. Temperature

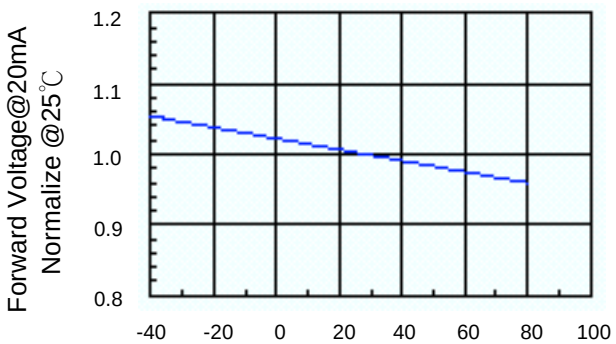


Fig.4 Relative Intensity vs. Temperature

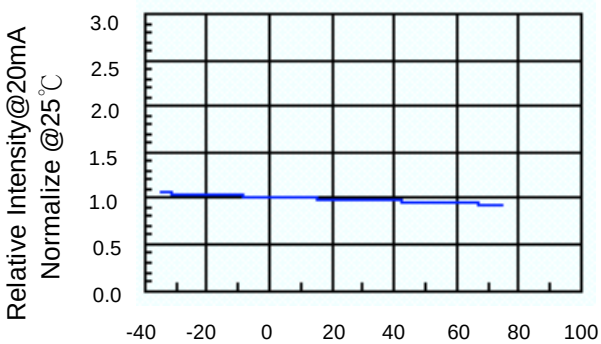


Fig.5 Relative Intensity vs. Wavelength

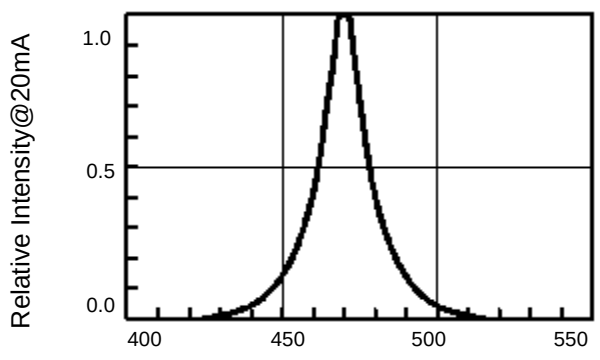
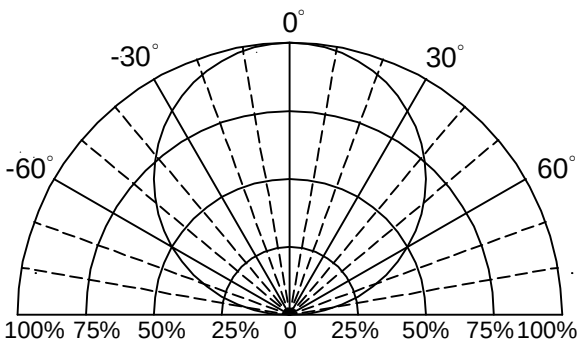


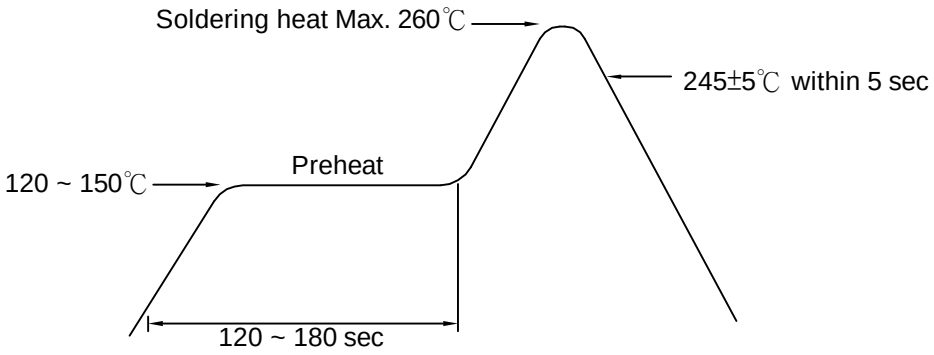
Fig.6 Directive Radiation



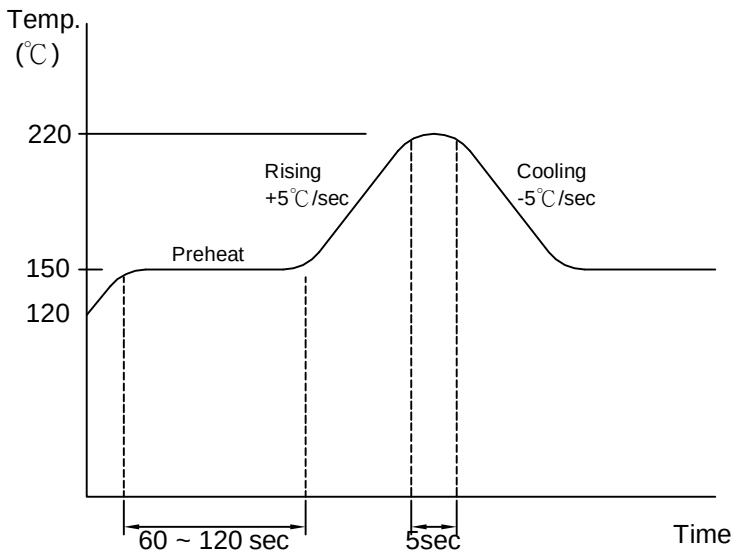
Soldering Iron:

Basic spec is ≦5 sec when 260℃. If temperature is higher, time should be shorter(+10℃ → -1sec).
Power dissipation of iron should be smaller than 15W,and temperature should be controllable.
Surface temperature of the device should be under 230℃.

Soldering heat



Reflow Temp/Time



Precautions For Use:

Storage time:

1.The operation of Temperatures and RH are : 5℃~35℃,RH<60%.

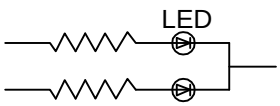
2.Once the package is opened, the products should be used within a week.
Otherwise, they should be kept in a damp proof box with descanting agent.
Considering the tape life, we suggest our customers to use our products within a year(from production date).

3.If opened more than one week in an atmosphere 5℃ ~ 35℃,RH<60%,
they should be treated at 60℃±5 ℃fo r 15hrs.

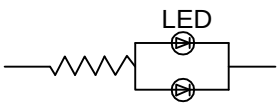
Drive Method:

LED is a current operated device, and therefore, requirer some kind of current limiting incorporated into the driver circuit. This current limiting typically takes the form of a current limiting resistor placed in series with the LED.
Consider worst case voltage variations than could occur across the current limiting resistor. The forwrd current should not be allowed to change by more than 40 % of its desired value.

Circuit model A



Circuit model B



(A) Recommended circuit.
(B) The difference of brightness between LED could be found due to the VF-IF characteristics of LED.

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED.

ESD(Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing these LED. All devices, equipment and machinery must be properly grounded.

Reliability Test:

Classification	Test Item	Test Condition	Reference Standard
Endurance Test	Operating Life Test	1.Ta=Under Room Temperature As Per Data Sheet Maximum Rating. 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	MIL-STD-750D: 1026 MIL-STD-883D: 1005 JIS C 7021: B-1
	High Temperature Storage Test	1.Ta=105℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	MIL-STD-883D:1008 JIS C 7021: B-10
	Low Temperature Storage Test	1.Ta=-40℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	JIS C 7021: B-12
	High Temperature High Humidity Storage Test	1.IR-Reflow In-Board, 2 Times 2.Ta=65℃±5℃ 3.RH=90％~95％ 4.t=1000hrs±2hrs	MIL-STD-202F:103B JIS C 7021: B-11
Environmental Test	Thermal Shock Test	1.IR-Reflow In-Board,2 times 2.Ta=105℃±5℃& -40℃±5℃ (10min) (10min) 3.total 10 cycles	MIL-STD-202F: 107D MIL-STD-750D: 1051 MIL-STD-883D: 1011
	Solder Resistance Test	1.T.Sol=260℃±5℃ 2.Dwell Time= 10±1sec.	MIL-STD-202F: 210A MIL-STD-750D: 2031 JIS C 7021: A-1
	Solderability Test	1.T.Sol=235℃±5℃ 2.Immersion time 2 ±0.5sec 3.Immersion rate 25 ±2.5mm/sec 4.Immersion rate 25 ±2.5mm/sec 5.Coverage ≧95% of the dipped surface	MIL-STD-202F: 208D MIL-STD-750D: 2026 MIL-STD-883D: 2003 IEC 68 Part 2-20 JIS C 7021: A-2
	Temperature Cycling	1.105℃ ~ 25℃ ~ 55℃ ~ 25℃ 30mins 5mins 30mins 5mins 2.10 Cyeles	MIL-STD-202F: 107D MIL-STD-750D: 1051 MIL-STD-883D: 1010 JIS C 7021: A-4
	Solderability Test	Ramp-up rate(183 ℃ to Peak) +3℃ second max Temp. maintain at 125(±25)℃ 120 seconds max Temp. maintain above 183 ℃ 60-150 seconds Peak temperature range 235 ℃+5-0℃ Time within 5 ℃ of actual Peak Temperature(tp) 10-30 seconds Ramp-down rate +6 ℃/second max	MIL-STD-750D:2031.2 J-STD-020